



Junction Temperature	T_j	135	
Storage Temperature	T_{stg}	-55~+125	
Soldering Temperature	T_{sol}	260	

: 100 μ s pulse, 100Hz frequency
 : AC for 1minute, R.H.=40~60%

(Temperature=25°C)

Parameter		Symbol	Condition	Min.	Typ.	Max.	Unit
Input	Forward Voltage	V_F	$I_F=10mA$	-	1.2	1.5	V
	Reverse Current	I_R	$V_R=6V$	-	-	1	μA
	Terminal Capacitance	C_t	$V=0, f=1MHz$	-	30	250	pF
	Collector-Emitter dark current	I_{CEO}	$V_{CE}=20V, I_F=0$	-	-	50	nA
Output	Collector-Emitter breakdown voltage	BV_{CEO}	$I_C=0.1mA, I_F=0$	80	-	-	V
	Emitter-Collector breakdown voltage	BV_{ECO}	$I_E=0.1mA, I_F=0$	7	-	-	V
	Current transfer ratio	CTR	$I_F=5mA, V_{CE}=5V$	80	-	600	%

Transfer Characteristics

<p>J</p> <p>JieJie Microelectronics Co., Ltd.</p>	<p>OC</p> <p>Opto Coupler</p>	<p>T</p> <p>Transistor</p>	<p>101</p> <p>Marketization Model</p>	<p>0</p> <p>CTR Rank:0/6/7/8/9</p>	<p>h</p> <p>h:Automotive grade</p>	<p>-L4</p> <p>LSOP4</p>	<p>/</p> <p>None:T1 R:T2</p>
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None/R	3000 Units/Reel

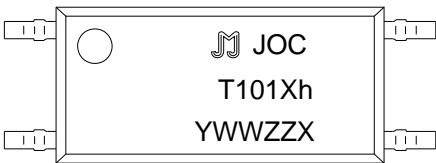
	<p><u>YWWZZX</u></p> <p>LOT NO.</p>
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FIG.1: Max. Allowable LED Forward Current vs. Ambient Temperature

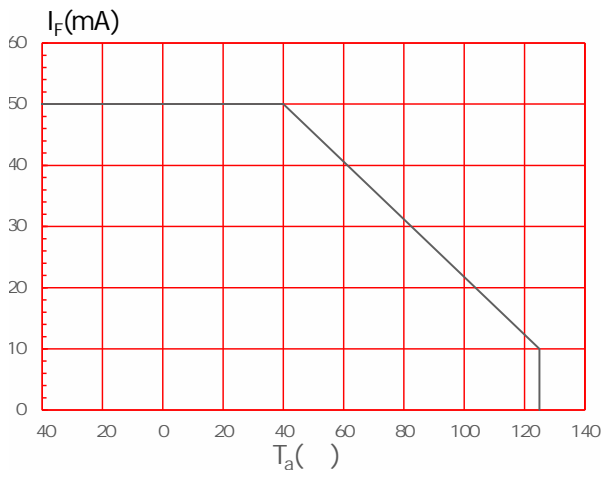


FIG.3: Forward Current vs. Forward Voltage



FIG.2: Collector Power Dissipation vs. Ambient Temperature

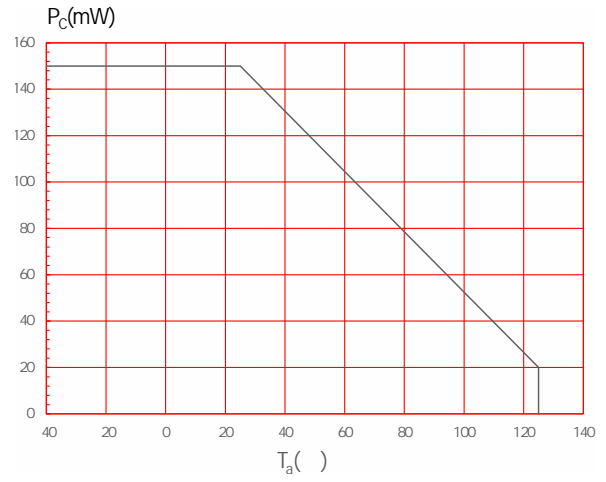


FIG.4: Normalized Collector Dark Current vs. Ambient Temperature

FIG.7: Normalized Current Transfer Ratio vs. Ambient Temperature

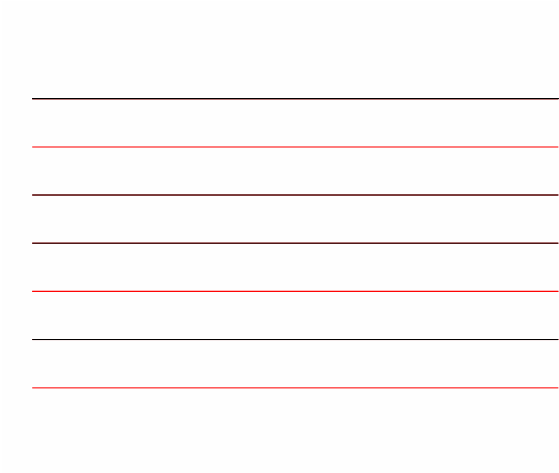


FIG.8: Normalized Collector-emitter Saturation Voltage vs. Ambient Temperature

FIG.11: Test Circuits of Response Time

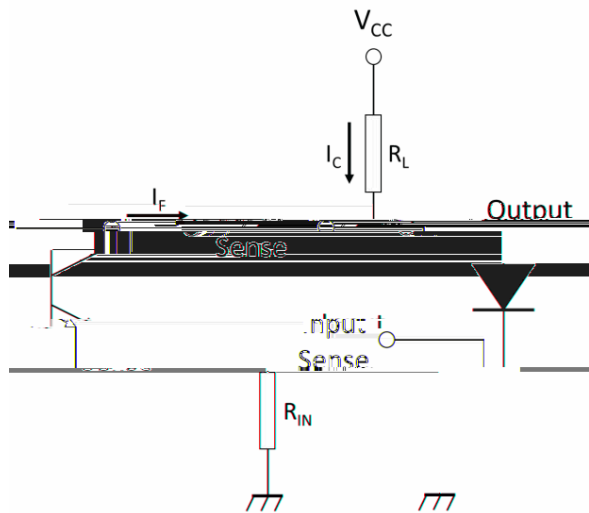


FIG.12: Curves of Response Time

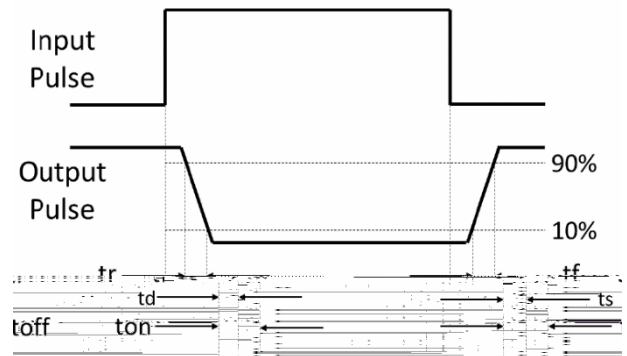
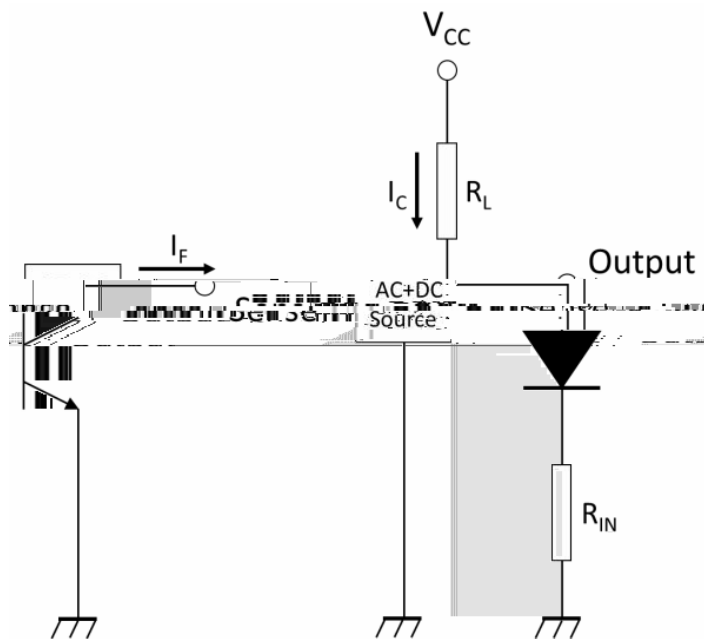
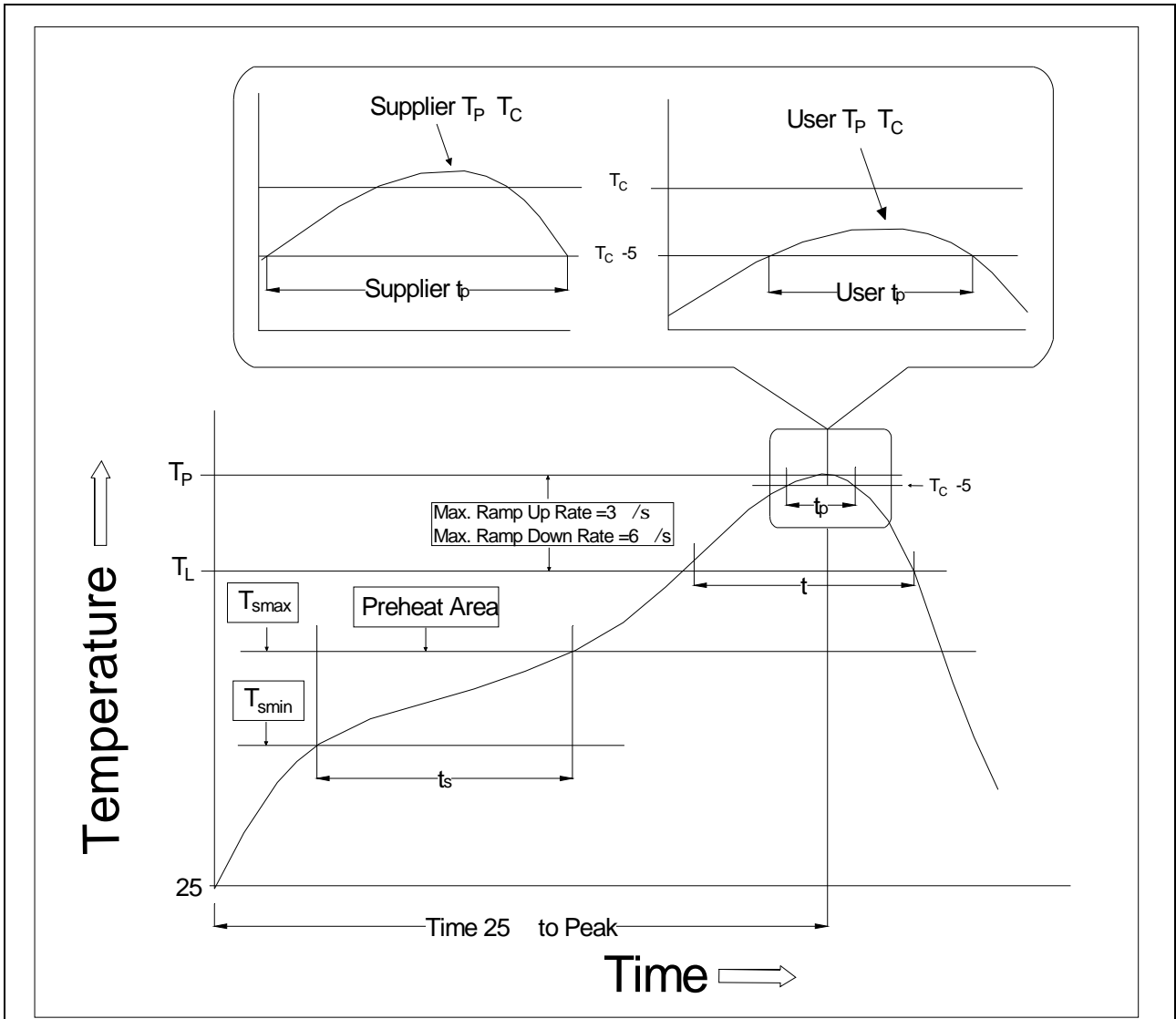


FIG.13: Test Circuits of Frequency Response



Ref.	Dimensions	
	Millimeters	Inches




Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (T _{smin})	100	150
Temperature Max. (T _{smax})	150	200
Time (t _s) from (T _{smin} to T _{smax})	60-120 seconds	60-120 seconds
Ramp-up Rate (t _L to t _P)	3 °/second max.	3 °/second max.
Liquidus Temperature (T _L)	183	217
Time (t _L) Maintained Above (T _L)	60-150 seconds	60-150 seconds
Peak Body Package Temperature	235 +0 /-5	260 +0 /-5
Time (t _P) within 5 ° of 260	20 seconds	30 seconds
Ramp-down Rate (T _P to T _L)	6 °/second max.	6 °/second max.
Time 25 ° to Peak Temperature	6 minutes max.	8 minutes max.

Note:

1. Reflow soldering is recommended at the temperatures and times shown, no more than three times.
2. Avoid direct contact between the epoxy body and any tools or surfaces exceeding its maximum storage temperature.
3. Application of pressure on the epoxy body is prohibited at elevated temperatures. In specific scenarios, any applied force must not exceed 2.5N.
4. Ensure the component has cooled to ambient temperature before proceeding with any subsequent manufacturing steps.
5. The component has a shelf life of one year when stored under standard conditions.
6. Recommend storage Temp.: 0~40°C;
Recommend storage humidity: <60%;
MSL level: MSL 1

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